TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HC166AP,TC74HC166AF,TC74HC166AFN

8-Bit Shift Register (P-IN, S-OUT)

The TC74HC166A is a high speed CMOS 8-BIT PARALLEL/SERIAL-IN, SERIAL-OUT SHIFT REGISTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

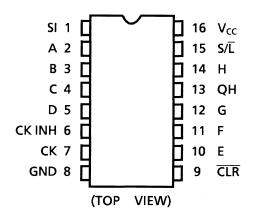
It consists of parallel-in or serial-in, serial-out 8-bit shift register with a gated clock input and an overriding clear input. The parallel-in or serial-in modes are controlled by the SHIFT/ $\overline{\text{LOAD}}$  input. When the SHIFT/ $\overline{\text{LOAD}}$  input is held high, the serial data input is enabled and the eight flip-flops perform serial shifting on each clock pulse. When held low, the parallel data inputs are enabled and synchronous loading occurs on the next clock pulse. Clocking is accomplished on the low-to-high transition of the clock pulse. The CK-INH input should be shifted high only while the CK input is held high. A direct clear input overrides all other inputs, including the clock, and sets all the flip-flops to zero. Functional details are shown in the truth table and the timing charts.

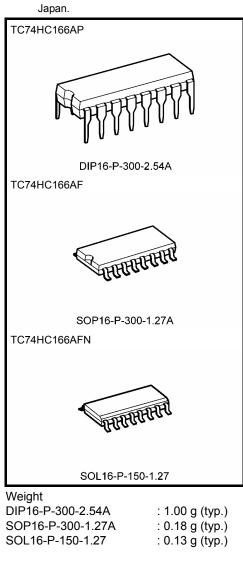
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

- High speed:  $f_{max} = 57 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Output drive immunity: 10 LSTTL loads
- Symmetrical output impedance: |I<sub>OH</sub>| = I<sub>OL</sub> = 4 mA (min)
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 to 6 V
- Pin and function compatible with 74LS166

#### **Pin Assignment**

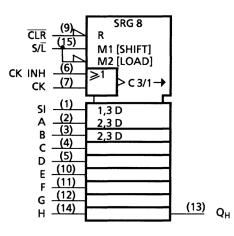




Note: xxxFN (JEDEC SOP) is not available in Japan

## TOSHIBA

### **IEC Logic Symbol**



## **Truth Table**

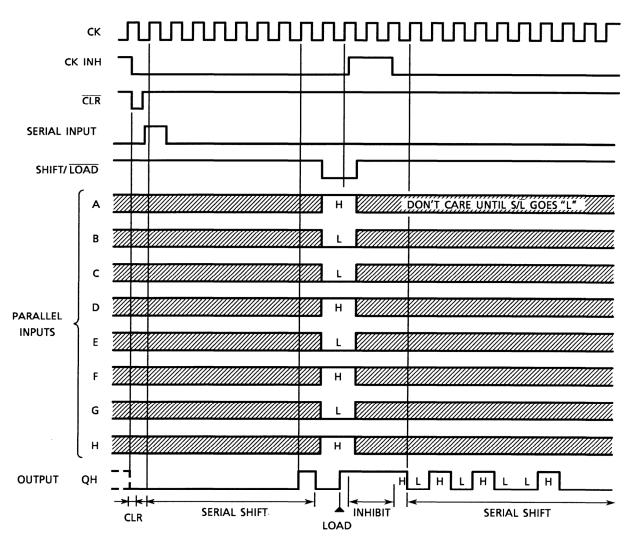
			ernal puts	Output						
	SHIFT/ LOAD	CK INH.	СК	SERIAL IN	PARALLEL A·····H	QA QB (		QH		
L	Х	Х	Х	Х	Х	L	L	L		
Н	Х	Х	$\rightarrow$	Х	Х	No Change				
Н	L	L		Х	a····h	а	b	h		
Н	Н	L		Н	Х	Н	QAn	QGn		
Н	Н	L		L	Х	L QAn		QGn		
Н	Х	Н	Х	Х	Х		nge			

#### X: Don't care

a $\cdots$ h: The level of steady state input voltage at inputs A through H respectively

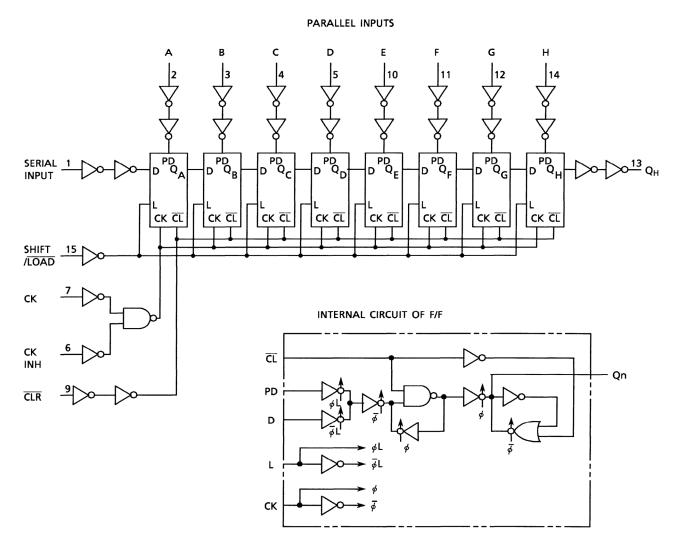
# **TOSHIBA**

#### **Timing Chart**



# <u>TOSHIBA</u>

## System Diagram



### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	–0.5 to 7	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	lıĸ	±20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	IOUT	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2 to 6	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 ( $V_{CC} = 6.0 \text{ V}$ )	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
	,			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
		—		2.0	1.50	—	_	1.50	_	
High-level input voltage	VIH			4.5	3.15	—	—	3.15	—	V
Ŭ				6.0	4.20		_	4.20	_	
				2.0	_	—	0.50	—	0.50	
Low-level input voltage	VIL			4.5	_	—	1.35	—	1.35	V
Ŭ				6.0			1.80	_	1.80	
	Vон	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	1.9	2.0	—	1.9	—	
			$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	—	4.4	—	
High-level output voltage				6.0	5.9	6.0		5.9		V
Ũ			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31		4.13		
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63		
				2.0		0.0	0.1		0.1	
			$I_{OL} = 20 \ \mu A$	4.5	—	0.0	0.1	—	0.1	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		6.0		0.0	0.1	_	0.1	V
5			$I_{OL} = 4 \text{ mA}$	4.5		0.17	0.26	_	0.33	
			I <sub>OL</sub> = 5.2 mA	6.0	_	0.18	0.26	—	0.33	
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0			±0.1		±1.0	μA
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or	GND	6.0		_	4.0		40.0	μΑ

### Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 to 85°C	Unit
			V <sub>CC</sub> (V)	Тур.	Limit	Limit	
Minimum pulse width	twan		2.0		75	95	
(CK)	t <sub>W (H)</sub>	—	4.5	—	15	19	ns
	t <sub>W (L)</sub>		6.0	_	13	16	
Minimum pulse width			2.0	—	75	95	
(CLR)	t <sub>W (L)</sub>	—	4.5	—	15	19	ns
			6.0		13	16	
Minimum set-up time			2.0	—	75	95	
(SI, PI)	ts	—	4.5	—	15	19	ns
			6.0		13	16	
Minimum set-up time	ts		2.0	—	75	95	
(S/L)		—	4.5	—	15	19	ns
			6.0	_	13	16	
Minimum hold time			2.0	—	0	0	
(SI, PI)	t <sub>h</sub>	—	4.5	—	0	0	ns
			6.0	_	0	0	
Minimum hold time			2.0	—	0	0	
(S/L)	t <sub>h</sub>	—	4.5	—	0	0	ns
			6.0	_	0	0	
Minimum removal time			2.0	—	50	65	
(CLR)	t <sub>rem</sub>	—	4.5	—	10	13	ns
			6.0	_	9	11	
			2.0	—	6	5	
Clock frequency	f	—	4.5	—	31	25	MHz
			6.0		36	29	

## AC Characteristics (C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> t <sub>THL</sub>	_	_	4	8	ns
Propagation delay time (CK-QH)	<sup>t</sup> pLH t <sub>pHL</sub>	—	_	16	26	ns
Propagation delay time ( CLR -QH)	t <sub>pHL</sub>	—	_	15	24	ns
Maximum clock frequency	f <sub>max</sub>	—	33	57		MHz

## AC Characteristics (C<sub>L</sub> = 50 pF, input: $t_r = t_f = 6$ ns)

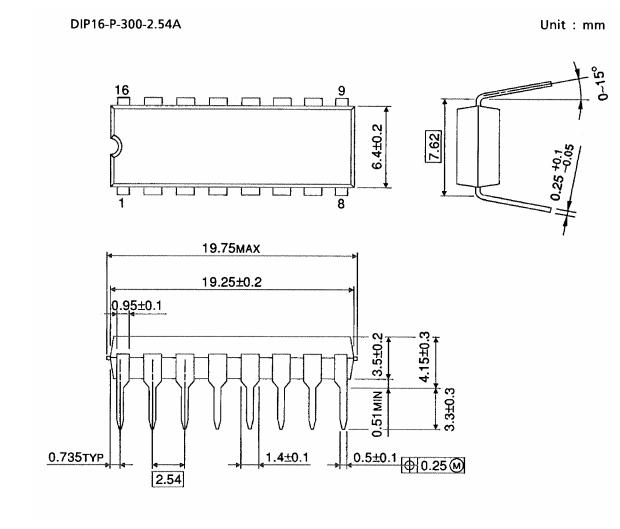
Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C		Unit	
			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Output transition time	t <sub>TLH</sub>		2.0 4.5	_	30 8	75 15	_	95 19	20
Output transition time	t <sub>THL</sub>		4.5 6.0	_	8 7	15	_	19	ns
Dropogation delay time	4		2.0	_	70	150	_	190	
Propagation delay time	t <sub>pLH</sub>	—	4.5	—	20	30	—	38	ns
(CK-QH)	t <sub>pHL</sub>		6.0	—	16	26	—	32	
Drene nation delau time	ie t <sub>pHL</sub>		2.0	_	60	135	_	170	
Propagation delay time $(\overline{\text{CLR}} - \text{QH})$		_	4.5	_	18	27	_	34	ns
(CLR -QH)			6.0	—	14	23	—	29	
			2.0	6	14	_	5		
Maximum clock frequency	f <sub>max</sub>	—	4.5	31	50	—	25	—	MHz
			6.0	36	63	—	29	—	
Input capacitance	C <sub>IN</sub>	_			5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	60	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **Package Dimensions**



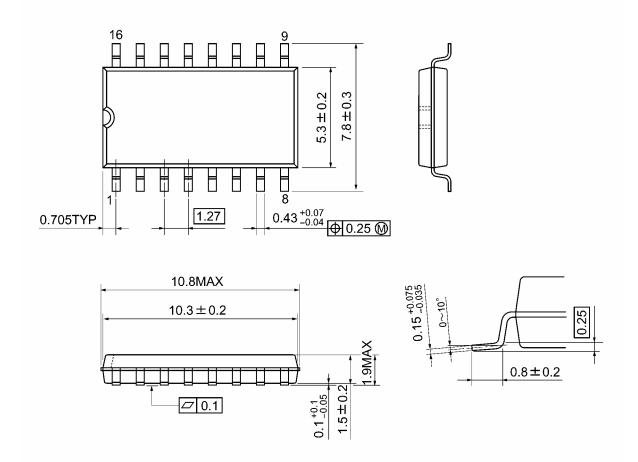
Weight: 1.00 g (typ.)



#### **Package Dimensions**

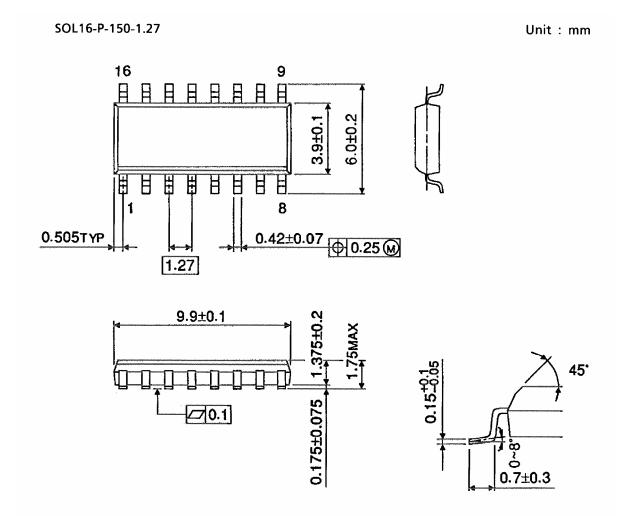
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

## Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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